

## Multi-Protocol Wireless Module with PA



### **Key Features**

- Microcontroller
  - Powerful ARM Cortex-M4F processor
  - Powerful 48-MHz Arm® Cortex®-M4F processor
  - 352KB of in-system Programmable Flash
  - 256KB of ROM for protocols and library functions
  - > 8KB of Cache SRAM (Alternatively available as general-purpose RAM)
  - 80KB of ultra-low leakage SRAM. The SRAM is protected by parity to ensure high reliability of operation.
  - ➤ 2-Pin cJTAG and JTAG debuggingRF performance
  - Supports Over-the-Air upgrade (OTA)
- Ultra-low power sensor controller with 4KB of SRAM
  - Sample, store, and process sensor data
  - Operation independent from system CPU
  - Fast wake-up for low-power operationBQB, FCC, CE, RoHS compliant
- TI-RTOS, drivers, Bootloader, Bluetooth® 5 Low Energy Controller, and IEEE 802.15.4 MAC in ROM for optimized application size
- Peripherals
  - Digital peripherals can be routed to any GPIO
  - 4× 32-bit or 8× 16-bit general-purpose timers
  - > 12-Bit ADC, 200 kSamples/s, 8 channels
  - > 2× comparators with internal reference DAC
  - (1× continuous time, 1× ultra-low power)
  - Programmable current source
  - 2× UART
  - > 2× SSI (SPI, MICROWIRE, TI)
  - ▶ 12C
  - ► 12S
  - Real-Time Clock (RTC)
  - > AES 128- and 256-bit Crypto Accelerator
  - ECC and RSA Public Key Hardware Accelerator
  - SHA2 Accelerator (Full suite up to SHA-512)
  - True Random Number Generator (TRNG)



- Capacitive sensing, up to 8 channels
- Integrated temperature and battery monitor
- External system
  - On-chip Buck DC/DC converter
- Low power
  - Wide supply voltage range: 1.8 V to 3.8 V
  - Active-Mode RX: 6.9 mA
  - Active-Mode TX 0 dBm: 7.3 mA
  - Active-Mode TX 5 dBm: 9.6 mA
  - Active-Mode TX at +10 dBm: 22 mA
  - > Active-Mode TX at +20 dBm: 85 mA
  - Active-Mode MCU 48 MHz (CoreMark):
  - > 3.4 mA (71  $\mu$ A/MHz)
  - > Sensor Controller, Low Power-Mode, 2 MHz, running infinite loop: 30.1 μA
  - Sensor Controller, Active-Mode, 24 MHz, running infinite loop: 808 μΑ
  - > Standby: 0.94 μA (RTC on, 80KB RAM and CPU retention)
  - Shutdown: 150 nA (wakeup on external events)
- Radio section
  - 2.4 GHz RF transceiver compatible with Bluetooth 5 Low Energy and IEEE 802.15.4 PHY and MAC
  - Excellent receiver sensitivity:
  - > 100 dBm for 802.15.4 (2.4 GHz),
  - → -105 dBm for Bluetooth 125-kbps (LE Coded PHY)
  - Output power up to +20 dBm with temperature compensation
  - > Suitable for systems targeting compliance with worldwide radio frequency regulations
- Wireless protocols
  - `Thread, Zigbee®, Bluetooth® 5 Low Energy, IEEE 802.15.4g, IPv6-enabled smart objects (6LoWPAN), Wi-SUN®, proprietary systems, SimpleLink™ TI 15.4-Stack (2.4 GHz), and Dynamic Multiprotocol Manager (DMM) driver.
- Size: 29.86 mm x 19.98 mm x 2.15 mm (With Shielding)
- FCC, CE Compliant

### **Descriptions**

BDE-RFM207 is a multiprotocol 2.4G wireless module targeted at low power sensors and PC/Phone accessories. It supports Thread, Zigbee, Bluetooth 5 Low Energy, IEEE 802.15.4g, IPv6-enabled smart objects (6LoWPAN), Wi-SUN, proprietary systems, SimpleLink TI 15.4-Stack (2.4 GHz), and Dynamic Multiprotocol Manager (DMM) driver.

BDE-RFM207P has an integrated power amplifier, which enable 20 dBm output power.



BDE-RFM207 highly integrates radio, stack, profile and applications in a SoC, without the need of using an external MCU. The module also offers flexible hardware interfaces for the sensor application.

It enables ultra-low power connectivity and data transfer for the applications that are sensitive to power consumption, size and cost.

## **Block Diagram**

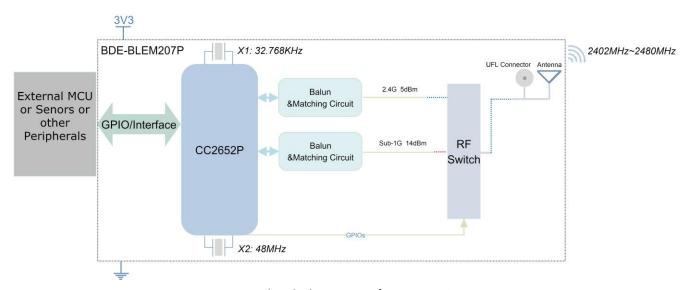


Fig. 1: The Block Diagram of BDE-RFM207P

# **Applications**

- 2400 to 2480 MHz ISM and SRD systems with down to 4 kHz of receive bandwidth
- Building automation
- Grid infrastructure
- Industrial transport asset tracking
- Factory automation and control
- Medical
- Electronic point of sale (EPOS) Electronic Shelf Label (ESL)



## **Electrical Characteristics**

#### ■ Absolute maximum rating

Rating	Min	Тур	Max	Unit	Notes
Storage Temperature	-40	-	125	$^{\circ}$	
VDD	-0.3	-	4.1	٧	
Other Digital Terminals	-0.3	-	VDDS+0.3≤4.1	V	
Voltage on ADC input	-0.3	-	VDDS	V	Voltage scaling enabled
	-0.3	-	1.49	V	Voltage scaling disabled, internal reference
	-0.3	-	VDDS/2.9	V	Voltage scaling disabled, VDDS as reference
RF pin	-	-	2	dBm	

#### ■ Recommended operating conditions

Rating	Min	Тур	Max	Unit
Operating Temperature	-40	-	85	${\mathbb C}$
VDD	2.1	3.3	3.8	V



### **Pinout**

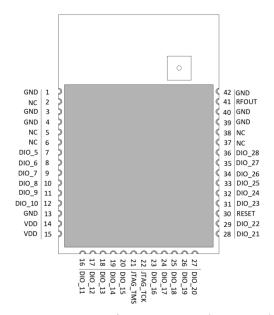


Fig. 2: The pinout of BDE-RFM207P (TOP VIEW)
Table 1: Pin definitions of BDE-RFM207P

Pin Number	Pin Name	Definitions	
1	GND	Power Ground	
2	NC	NC	
3	GND	Power Ground	
4	GND	Power Ground	
5	NC	NC	
6	NC	NC	
7	DIO_5	GPIO, High-drive Capability	
8	DIO_6	GPIO, High-drive Capability	
9	DIO_7	GPIO, High-drive Capability	
10	DIO_8	GPIO	
11	DIO_9	GPIO	
12	DIO_10	GPIO	
13	GND	Power Ground	
14	VDD	Supply Power	
15	VDD	Supply Power	
16	DIO_11	GPIO	
17	DIO_12	GPIO	
18	DIO_13	GPIO	
19	DIO_14	GPIO	
20	DIO_15	GPIO	
21	JTAG_TMSC	JTAG TMSC, High-drive Capability	
22	JTAG_TCKC	JTAG TCKC	
23	DIO_16	GPIO, JTAG_TDO, High-drive Capability	



24	DIO_17	GPIO, JTAG_TDI, High-drive Capability
25	DIO_18	GPIO
26	DIO_19	GPIO
27	DIO_20	GPIO
28	DIO_21	GPIO
29	DIO_22	GPIO
30	RESET	Reset, Active Low
31	DIO_23	GPIO, Analog Capability
32	DIO_24	GPIO, Analog Capability
33	DIO_25	GPIO, Analog Capability
34	DIO_26	GPIO, Analog Capability
35	DIO_27	GPIO, Analog Capability
36	DIO_28	GPIO, Analog Capability
37	NC	NC
38	NC	NC
39	GND	Power Ground
40	GND	Power Ground
41	RFOUT	2.4G RF Output Port
42	GND	Power Ground

### **Overall Dimensions**

Fig. 3 shows the overall dimensions of BDE-RFM207P. The module measures 29.86mm long by 19.97mm wide by 2.15mm high with the shield.

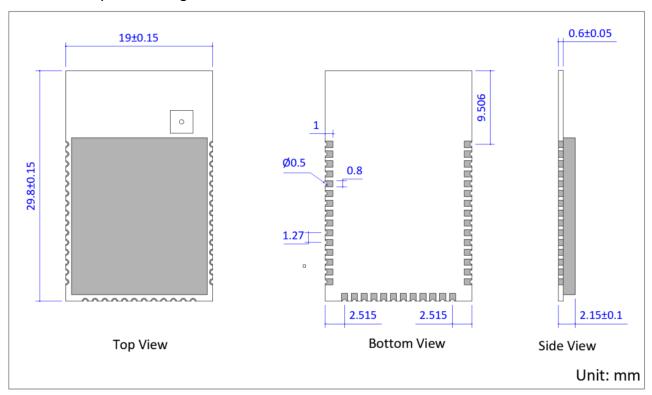




Fig. 3: Overall Dimensions of BDE-RFM207P

#### **Module Location**

In order to get a fine performance when integrate the module to your product, it is advised to use the recommended module location to the respective PCB.

#### ■ Location in X-Y plane

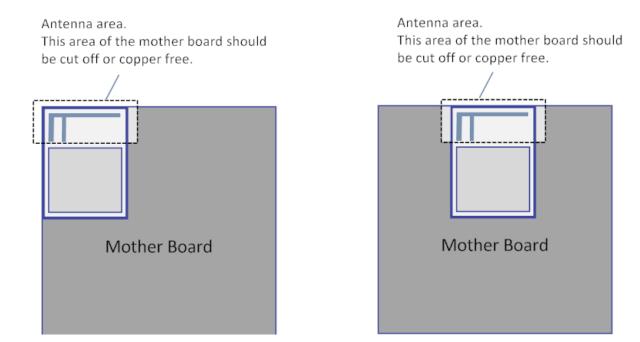


Fig. 4: Recommended location in X-Y plane

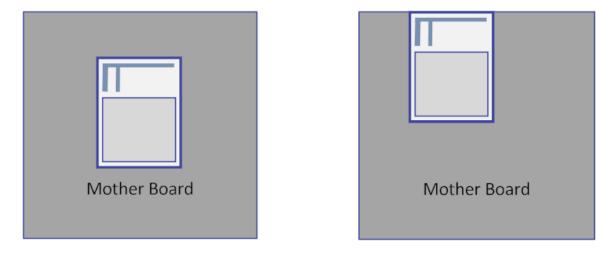


Fig. 5: Not recommended location in X-Y plane



#### ■ Location in Z plane

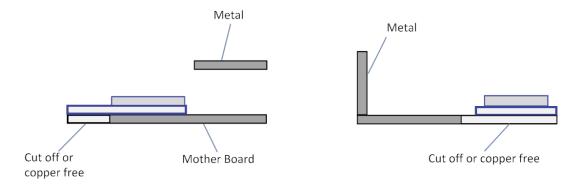


Fig. 6: Recommended location in Z plane

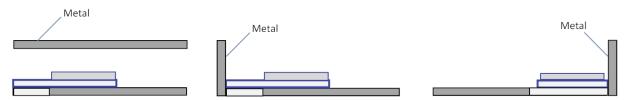


Fig. 7: Not recommended location in Z plane

# **Typical Solder Reflow Profile**

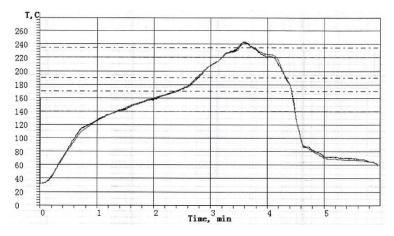


Fig. 8: Typical Solder Reflow Profile



## **Package Information**



Fig. 9: Package

### **Contacts**

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